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Mikheev, Konstantin G.; Saushin, Aleksandr S.; Zonov, Ruslan G.; Nasibulin, Albert G.; Mikheev, Gennady M. **Photon-drag in single-walled carbon nanotube and silver-palladium films**

Published in: Journal of Nanophotonics

DOI: 10.1117/1.JNP.10.012505

Published: 31/03/2016

Document Version Publisher's PDF, also known as Version of record

Please cite the original version:

Mikheev, K. G., Saushin, A. S., Zonov, R. G., Nasibulin, A. G., & Mikheev, G. M. (2016). Photon-drag in singlewalled carbon nanotube and silver-palladium films: The effect of polarization. *Journal of Nanophotonics*, *10*(1), 1-9. Article 012505. https://doi.org/10.1117/1.JNP.10.012505

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Konstantin G. Mikheev Aleksandr S. Saushin Ruslan G. Zonov Albert G. Nasibulin Gennady M. Mikheev



Photon-drag in single-walled carbon nanotube and silver-palladium films: the effect of polarization

Konstantin G. Mikheev,^{a,*} Aleksandr S. Saushin,^a Ruslan G. Zonov,^a Albert G. Nasibulin,^{b,c,d} and Gennady M. Mikheev^a

^aInstitute of Mechanics Ural Branch of Russian Academy of Sciences, ul. T. Baramzinoy 34, Izhevsk 426067, Russia

^bAalto University, Department of Applied Physics, P.O. Box 11100, Espoo,

FI-00076 AALTO, Finland

^cSt. Petersburg Polytechnic University, 29, Polytechnicheskaya Street,

St. Petersburg 195251, Russia

^dSkolkovo Institute of Science and Technology, Skolkovo, Nobel Street 3, Moscow 143026, Russia

Abstract. Polarization influence on the photovoltaic current raised due to the photon-drag effect in the single-walled carbon nanotube (SWNT) films and nanostructured silver-palladium (Ag/ Pd) resistive films is examined at the wavelengths of 532 and 1064 nm of nanosecond laser pulses. The SWNT films were synthesized by the aerosol chemical vapor deposition technique. Ag/Pd films, consisting of AgPd alloy and palladium oxide (PdO), were prepared by burning a special paste on a ceramic substrate. The films obtained were characterized by Raman spectroscopy. It is shown that the Ag/Pd films Raman spectra consist of PdO peak that moves from 650 cm^{-1} to 628 cm^{-1} as the excitation He-Ne laser power increases. The photocurrent was measured at the oblique incidence of the laser beam on the film in the direction perpendicular to the plane of incidence. It is found that the transverse photocurrent in the SWNT films at circular polarization is absent and does not depend on the direction of the electric field vector rotation (the sign of the circular polarization) of the incident irradiation. The photocurrent in the Ag/Pd films at circular polarized irradiation is significant and depends on the circular polarization sign. The results obtained demonstrate the potential applications of the Ag/Pd resistive films as a sensor of the circular polarization sign of the incident light pulse in a wide wavelength range. © 2015 Society of Photo-Optical Instrumentation Engineers (SPIE) [DOI: 10.1117/1.JNP.10.012505]

Keywords: photon-drag effect; single-walled carbon nanotube film; silver-palladium resistive film; Raman spectroscopy; laser pulse; transverse photocurrent; photocurrent; circular polarization sign.

Paper 15073SSP received Aug. 3, 2015; accepted for publication Sep. 15, 2015; published online Nov. 5, 2015.

1 Introduction

The photovoltaic current generation, depending on the direction of the wave vector and the polarization of incident laser radiation, is observed in various nanocarbon film materials [nanographite films, graphene, and single-walled carbon nanotube (SWNT) films].^{1–3} Similar phenomena have been observed in quantum wells,⁴ gold films of nanometer thickness with different morphologies,^{5,6} and also in nanostructured Ag/Pd resistive films.⁷ The photovoltaic current dependence on the direction of the wave vector in centrosymmetrical media can be explained by the photon-drag effect, which is observed both at linear and circular polarizations.⁸ The study of polarization influence on the photon-drag effect in different film structures is of interest in terms of developing and creating the polarization analyzers, operating on new principles.^{9,10}

^{*}Address all correspondence to: Konstantin G. Mikheev, E-mail: k.mikheev@udman.ru

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The aim of this paper is to carry out the comparative study of a photovoltaic signal due to the photon-drag effect in SWNT films and Ag/Pd films as a function of the polarization ellipticity and the rotation direction of the electrical field vector of the incident laser radiation.

2 Materials

2.1 Brief Description of the Production Technology of the Single-Walled Carbon Nanotube Films

SWNT film is a new material with a number of unique properties. They are widely used in photonics and optoelectronics. There are a large number of papers showing the possibility of using the SWNT films for passive Q-switching of lasers in order to obtain picosecond and femtosecond laser pulses in a wide spectral range (see review^{11,12}). The sensors of bolometric detectors,¹³ photovoltaic converters of visible light,¹⁴ and organic solar cells¹⁵ are developing based on the SWNT films.

SWNTs were synthesized by an aerosol (floating catalyst) method based on thermal decomposition of ferrocene vapor in a carbon monoxide (CO) atmosphere.¹⁶ The synthesis was carried in a scaled-up version of the reactor with a tube of 150 mm in diameter and 1.5 m in length at a total CO flow rate of 4 L/min (with 1% volumetric content of CO_2) and at a temperature of 880°C.¹⁷ Ferrocene was evaporated at room temperature and thermally decomposed in a high temperature gradient resulting in the supersaturated conditions, formation of nanoparticles, and subsequent CO decomposition on the surface of catalyst particles leading to the SWNT growth. The synthesized SWNTs were collected downstream of the reactor by passing the aerosol flow through nitrocellulose membrane filters to form SWNT films, which were transferred from the low adhesive force filter to a polyethylene terephthalate (PET) substrate by a simple room temperature press transfer process.¹⁸ The SWNT collection time was varied from 3 to 30 min, which corresponded to the SWNT film thickness change from 25 to 625 nm and film transmittance from 94% to 22%.

2.2 Brief Description of the Production Technology of Ag/Pd Films

Ag/Pd resistive films have stable electrical characteristics and have long been used in electronics.¹⁹ They are widely applied for obtaining hybrid microcircuits, multicrystal modules, integrated circuits assemblies, and passive electronic components such as resistors, inductive elements, and multilayer capacitors.²⁰ Recently, it was shown that Ag/Pd resistive films can be used as photovoltaic converters which are sensitive to the direction of the incident radiation wave vector. It is established that they can operate as such convertors in a wide spectral range from 266 to 1064 nm.²¹

The Ag/Pd films are produced using technologies²² based on burning a special paste which contains silver oxide and palladium on the insulating substrate surface at high temperatures. The applied paste layer is dried and fired, i.e., is subjected to heat treatment, which imparts certain electrical and mechanical properties to the film. The paste includes functional, structural, and technological components. The functional component is the principal one determining the basic properties of the obtained films and consists of silver oxide (Ag_2O) and palladium. The structural component represents finely divided particles of glass, e.g., STs-273 glass, whose melting temperature is lower than the burning temperature. During burning, molten glass wets functional component particles with the suspension formation. After cooling and hardening, a mechanically strong film is formed, within which the quasihomogeneous distribution of functional phase particles takes place. The technological component is a "binder" which imparts certain viscosity and plasticity to the paste. This component contains organic substances (e.g., lanolin, colophony) and a certain solvent. The latter is evaporated during drying, the organic materials decompose and burn down during burning, i.e., the technological component is removed. In the experiments, the Ag/Pd films obtained at different fusion temperatures (878, 1013, and 1113 K) were studied. Finished film obtained at a fusion temperature of 878 K is a porous material, with the pore radius being of from 25 to 500 nm [see Fig. 1(a)].^{23,24} As seen in Figs. 1(b) and 1(c), the film obtained at a



Fig. 1 Scanning electron microscope images of the resistive Ag/Pd films' surface obtained at different fusion temperatures: (a) 878, (b) 1013, and (c) 1113 K.

fusion temperature of 1013 K is less porous, and the film obtained at a fusion temperature of 1113 K is not porous. The film's size was $20 \times 20 \text{ mm}^2$ and the thickness was $20 \mu \text{m}$.

2.3 Characterization of the Films

Raman spectroscopy was used to characterize the SWNT and Ag/Pd films. It was carried out on the Raman spectrometer Labram HR800 using excitation at 632.8 nm, with the ×100 objective used. The maximal excitation power was 8 mW. In order to decrease this, the imbedded neutral filters were used. The Raman spectra of the SWNT and Ag/Pd films were obtained in the range of wavenumbers from 100 to 1700 cm⁻¹ and from 200 to 800 cm⁻¹, respectively. Absorbance spectrum of the SWNT films was measured using double-beam UV/VIS spectrometer PerkinElmer LAMBDA 650.

2.3.1 Single-Walled Carbon Nanotube Films

The absorbance spectrum measured from the SWNT film transferred on a PET substrate is presented in Fig. 2. The spectrum was obtained against an empty PET film. The Van Hove transition (at the wavelength range from 700 to 800 nm) of metallic SWNTs is clearly visible, indicating the high quality of the SWNTs' sample.¹⁶

Raman spectrum measured from the SWNT film on the PET substrate at a low laser power density of 0.4 kW/cm² (to avoid laser heating and modification of the SWNT film^{25,26}) shows the strong G band [Fig. 3(a)] and radial breathing modes (RBMs) [Fig. 3(b)]. The G band is related to the vibration of sp²-bonded carbon atoms in a two-dimensional hexagonal lattice of the graphite layer, while the D band corresponds to the presence of defects on the nanotube walls or amorphous carbon material; therefore, the intensity ratio of G and D bands (I_G/I_D) is used as a reflection of the SWNT samples' quality.²⁷ The I_G/I_D ratio of the SWNT film on the PET substrate is equal to 36, which shows the good quality of the SWNTs.²⁸

The RBMs correspond to the coherent vibration of the carbon atoms in the radial direction and are used to probe the nanotube diameter (d_t) through its frequency (ω_{RBM}) based on the



Fig. 2 Absorbance spectrum measured from the single-walled carbon nanotube (SWNT) films on the polyethylene terephthalate substrate (PET).



Fig. 3 Raman spectrum of the SWNT film on the PET substrate excited by 632.8 nm: (a) G and D bands and (b) RBMs. Excitation power density was 0.4 kW/cm².

well-established relationship of $\omega_{\text{RBM}} = 217.8/d_t + 15.7.^{29}$ When excited, the RBM peaks were mainly located in the range of 130 to 160 cm⁻¹, that corresponds to a diameter range of 2.1 ÷ 1.5 nm (see the upper x-axis) [Fig. 3(b)].

2.3.2 Ag/Pd Resistive Films

In Fig. 4, the Raman spectra of Ag/Pd films obtained from the same resistive pastes at different fusion temperatures are presented. One can see the strong sharp peak in the spectrum of the film obtained at the fusion temperature of 878 K. There is the same peak in the spectrum of the film obtained at the fusion temperature of 1013 K, but it is smaller and there is no such band in the spectrum of the film obtained at the fusion temperature of 1113 K. According to the literature data,^{30,31} this peak with a shift of 649 cm⁻¹ is associated with the PdO content in the film, so it is clear that the PdO content in the films decreases as the fusion temperature increases. We have established earlier²³ that the photosensitivity of the Ag/Pd films is directly connected with the fusion temperature of 1113 K do not possess this photovoltaic phenomenon. Thus, we can conclude that the photosensitivity of the Ag/Pd films is directly content of the Ag/Pd films is directly connected with the PdO content in the photosensitivity of the Ag/Pd films is directly connected with the PdO content in the photosensitivity of the Ag/Pd films is directly connected with the PdO content in the photosensitivity of the Ag/Pd films is directly connected with the PdO content in the photosensitivity of the Ag/Pd films is directly connected with the PdO content in them. These results agree with the x-ray structural analysis confirming the effect of the percentage content of the PdO on the photosensitivity of the Ag/Pd resistive films.²³

In Figs. 5(a) and 5(b), the Raman spectra of Ag/Pd resistive films produced at the fusion temperatures of 878 and 1013 K obtained at different excitation powers are presented. One can see that the PdO peak wavenumber shifts down and the PdO peak FWHM increases as



Fig. 4 Raman spectra of Ag/Pd films obtained from resistive paste of the same composition at different fusion temperatures excited by 632.8 nm. Excitation power was 0.1 mW.



Fig. 5 Raman spectra of Ag/Pd films produced at the fusion temperatures: (a) 878 and (b) 1013 K measured at different excitation power. (c) PdO peak wavenumber as a function of excitation power and (d) PdO peak FWHM as a function of excitation power.

the excitation power increases for both of the films [see Figs. 5(c) and 5(d)]. It is worth noting that this process is reversible, i.e., while the laser power decreases the PdO peak wavenumber shifts up and the PdO peak FWHM decreases up to the initial points. This suggests that PdO is affected by laser heating but is not destroyed.

3 Experimental Results

To study the photovoltaic properties of SWNT and Ag/Pd resistive films, each sample was provided with two parallel silver film electrodes which were arranged on the opposite sides of the square films (see Fig. 6). The photovoltaic properties of the films were studied using a laser generating 16 and 19 ns pulses at wavelengths of 532 and 1064 nm, respectively. The scheme of the experiments is presented in Fig. 6. The linearly polarized laser pulses were directed



Fig. 6 The scheme of the experiment: (1) quarter-wave plate, (2) the film; (3) electrodes, (4) oscilloscope; (*n*) normal to the film surface, (*k*) wave vector of incident radiation, (σ) plane of incidence, (α) angle of incidence, (n_e) optical axis of the quarter-wave plate ($n_e \perp n_o$), (x') vertical axis, and (*E*) electric field vector (*E*, $x' || \sigma$). The electrodes are parallel to the incidence plane σ . The pulse shape in the inset is shown for Ag/Pd films: (I) incident laser pulse shape and (II) shape of photovoltaic pulses appearing between electrodes.

through quarter-wave plate 1 on the films 2. The angle of radiation incidence on the film was 45 deg; the measuring electrodes 3 were parallel to the incidence plane σ . The linearly polarized laser radiation at the wavelengths of 532 or 1064 nm was converted into circularly polarized radiation by the proper quarter-wave plate. The angle γ of rotation of the quarter-wave plate set a light ellipticity and the sign of circular polarization, where γ is the angle between vertical axis x' and axis n_{e} perpendicular to the optical axis n_{e} of the quarter-wave plate, see Fig. 6. The photovoltaic signal (pulsed voltage amplitude) appearing between two electrodes upon exposure to light pulses was recorded using a broadband digital oscilloscope 4 (Tektronix TDS7704B) with an input resistance of 50 Ω . The electric voltage pulse U_y was characterized by the duration and voltage defined as $U_y = gA$, where g is the polarity (g = +1 or -1) and A is the amplitude $(A \ge 0)$. The typical shape of photovoltaic pulses is shown in Fig. 6 (inset). Ag/Pd films obtained at fusion temperatures of 1013 and 1113 K have not possessed photovoltaic properties due to the low PdO content, so we would discuss further the properties only of the Ag/Pd film obtained at a fusion temperature of 878 K. The photocurrent, which is due to the photon-drag effect, in the SWNT films nonmonotonically depends on the film thickness and has a maximum value at around 300–350 nm³, so the experiments were carried out using films with a thickness of 330 nm.

In view of the fact that U_y is linearly dependent on incident power P and independent of the irradiated area (at fixed P), it is possible to construct plots of the radiation power conversion factors $\eta_{\lambda} = U_y/P$ versus rotation angle γ for wavelengths of 532 and 1064 nm.

The experimental dependences of η_{λ} as a function of γ are presented in Fig. 7. As can be seen from Fig. 7, both for the SWNT films and Ag/Pd films, the maximum absolute value $|\eta_{\lambda}^{\text{max}}|$ of factor η_{λ} decreases with increasing frequency (decreasing wavelength λ) of the incident radiation. For the both type of films at $\gamma = 0$, 90, and 180 deg (*p*-polarization), the response signal is absent (additional measurements showed that this signal is also absent for the *s*-polarized radiation). Moreover, the signal at circular polarization for SWNT films is equal to zero. For Ag/Pd films irradiated by radiation at the wavelengths of $\lambda = 1064$ nm or $\lambda = 532$ nm, the signal is positive for the right-hand (clockwise) polarization and negative for the left-hand (anticlockwise) polarization [Fig. 7(a)]. Thus, there is a direct effect of the circular polarization sign on the signal polarity. On the experimental dependences obtained for SWNT films [Fig. 7(b)] with both right-and left-hand polarized light and the phase angle varied within $0 < \gamma < 90$ deg and 90 deg $< \gamma < 180$ deg, respectively, the signal polarity takes both negative and positive values. To within the experimental error, all four experimental dependences presented in Fig. 7 obey the following relation: $\eta_{\lambda}(90 \text{ deg }-\gamma) = -\eta_{\lambda}(90 \text{ deg }+\gamma)$, where $0 < \gamma < 90$ deg, so that functions $\eta(\gamma)$ are antisymmetric relative to axis $\gamma = 90$ deg.



Fig. 7 Plots of conversion coefficient $\eta(\gamma)$ of pulsed laser radiation power into pulsed electric voltage versus phase angle γ of a quarter-wave plate for (a) $\lambda = 1064$ nm, (b) $\lambda = 532$ nm, for (1) SWNT and (2) Ag/Pd films; points represent experimental data, curves show the approximating functions $\eta_{\lambda} = \eta_{\lambda}^{(1)} \sin(2\gamma) - \eta_{\lambda}^{(2)} \sin(4\gamma)$. The top insets show polarization ellipses corresponding to various phase angles γ .

All experimental dependences presented in Fig. 7 are approximated by the following function:

$$\eta_{\lambda} = \eta_{\lambda}^{(1)} \sin(2\gamma) - \eta_{\lambda}^{(2)} \sin(4\gamma),$$

where $\eta_{\lambda}^{(1)}$ and $\eta_{\lambda}^{(2)}$ are the positive factors characterizing the circular and linear contributions³² that depend on the radiation wavelength. We found conversion factor η_{λ} both for SWNT and for Ag/Pd films at two wavelengths. For Ag/Pd films at $\lambda = 532$ nm, the conversion factors are equal to $\eta_{\lambda=532}^{(1)} = 24.2$ and $\eta_{\lambda=532}^{(2)} = 13$ mV/MW, while for the SWNT films $\eta_{\lambda=532}^{(1)} = 0$, $\eta_{\lambda=532}^{(2)} = 10$ mV/MW. When the radiation wavelength is enhanced to 1064 nm, the circular contribution in Ag/Pd films significantly increases in comparison with the linear contribution that considerably changes the form of the dependence; in this case, the factors are equal to $\eta_{\lambda=1064}^{(1)} = 63.2$ and $\eta_{\lambda=1064}^{(2)} = 14.6$ mV/MW. But in nanotube films, the signal insignificantly increases and the factors are equal to $\eta_{\lambda=1064}^{(1)} = 0$, $\eta_{\lambda=1064}^{(2)} = 12.2$ mV/MW. In other words, at both wavelengths in the nanotube films, the circular contribution is absent and the signal amplitude and polarity are defined by the orientation and the ratio of polarization ellipse axes. The similar results were obtained for the nanographite films.¹ This means that in contrast to the Ag/Pd-films, the SWNT films do not possess the sensitivity to the sign of circular polarization.

The results obtained for the nanographite and the SWNT films are in agreement with those obtained for the photon-drag effect study in graphene in the terahertz wavelength range.² The circular photon-drag effect in the terahertz range is interpreted as an ac Hall effect. According to Ref. 2, the proportional to $\sin 2\gamma$ circular contribution of the photon-drag current i_y in the direction of y, perpendicular to the incidence plane (see Fig. 6) in graphene, disappears at high frequencies of the incident radiation, which is confirmed by our experiments. However, the circular contribution of the drag current in Ag/Pd resistive films is significant in the visible and near-infrared regions. According to Ref. 23, Ag/Pd resistive films represent a porous structure of PdO and a solid solution of AgPd, consisting mainly of Ag, therefore, they have a complex energy structure. Thus, the theoretical description of the circular photon-drag effect in these films is a very difficult task, which is the subject of further research. Nevertheless, we believe that it is already possible to create sensors of the sign of circular polarization of pulsed laser radiation on the basis of resistive Ag/Pd films. According to our recent research, such a sensor can operate in the spectral range from 529 to 2940 nm.^{33,34}

4 Conclusion

The photocurrent of the photon-drag effect in the SWNT films in the direction perpendicular to the laser radiation incident plane depends on the orientation and ellipticity of the polarization ellipse of incident laser radiation, does not depend on the rotation direction of the electrical field vector, and vanishes at p-, s- polarizations as well as at the circular polarization of the incident radiation. With the same experimental geometry, the photocurrent of the photon-drag effect in the Ag/Pd films, consisting mainly of the AgPd alloy and PdO, vanishes at p-, s- polarizations, and depends on the ellipticity and the sign of the laser radiation circular polarization at the wavelengths of 532 and 1064 nm. The results obtained show the opportunity of applying the Ag/Pd films for the creation of the laser radiation circular polarization at wide spectral range.

Acknowledgments

This work was supported by the RFBR grants (Project No. 13-08-01031 and Project No. 13-02-96037 r_ural_a).

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Konstantin G. Mikheev is a researcher at the Institute of Mechanics Ural Branch Russian Academy of Sciences. He received his PhD in physics and mathematics in 2013. His research interests include the interaction of laser radiation with carbon nanomaterials and Raman spectroscopy.

Aleksandr S. Saushin graduated in 2012 at Izhevsk State Technical University. Currently, he is a researcher of the laser laboratory of the Institute of Mechanics in Izhevsk. His research interest includes the interaction of laser radiation with matter.

Ruslan G. Zonov is a senior researcher at Institute of Mechanics in Izhevsk. He received his PhD in physics and mathematics in 2006. He has over 40 scientific publications and four patents. His research interests associated with the high-power laser radiation interaction with thin metal and carbon films and studying of optoelectronic properties of these films.

Albert G. Nasibulin is a professor at Skolkovo Institute of Science and Technology and an adjunct professor at Aalto University School. He received his PhD in physical chemistry at Kemerovo State University and his Doctor of Science at Saint-Petersburg Technical State University. He has over 180 peer-reviewed scientific publications and 17 patents. He has specialized in the synthesis of nanomaterials, investigation of their growth mechanism, and potential applications in electronics and optoelectronics.

Gennady M. Mikheev graduated in 1981 at Moscow State University, where he also obtained his PhD in 1985. He obtained a DSc in 2000 from the Russian Academy of Science. Currently, he is a professor and the head of the laser laboratory of the Institute of Mechanics in Izhevsk. His research interest includes the interaction of laser radiation with matter.